



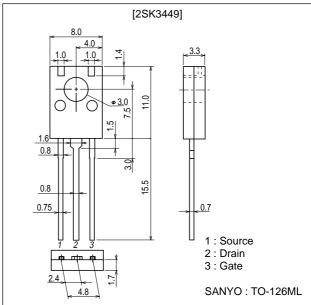
# **DC / DC Converter Applications**

### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

## **Package Dimensions**

unit : mm 2190



# **Specifications**

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		4.8	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	19.2	Α
Allowable Power Dissipation	PD		1	W
		Tc=25°C	10	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	60			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =60V, V <sub>GS</sub> =0			10	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	V <sub>GS</sub> (off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0		2.4	٧

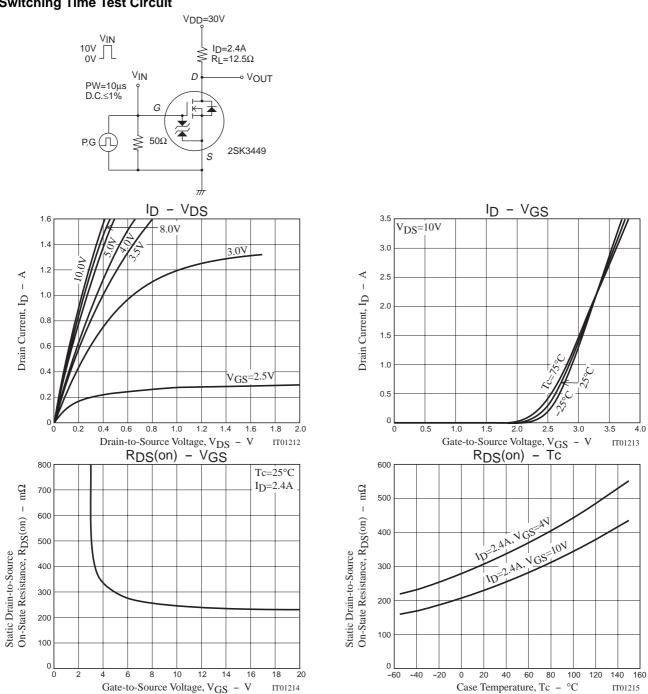
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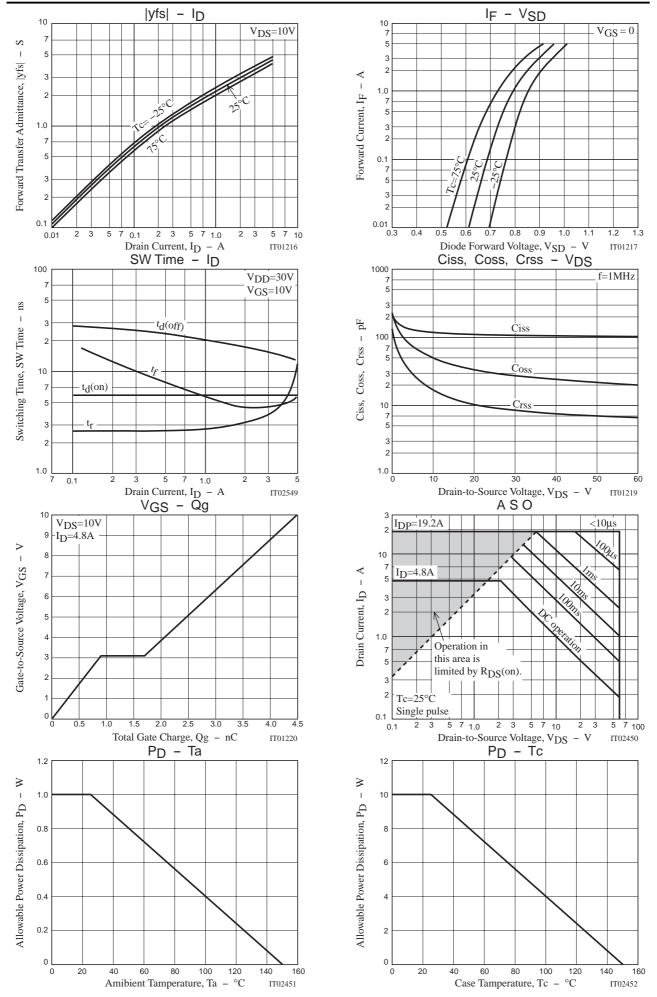
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Parameter	Symbol	Conditions	Ratings			Llmit
			min	typ	max	Unit
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =2.4A	2.2	3.2		S
Static Drain-to-Source On-State Resistance	RDS(on)1	I <sub>D</sub> =2.4A, V <sub>G</sub> S=10V		240	320	mΩ
	RDS(on)2	ID=2.4A, VGS=4V		320	440	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		110		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		35		pF
Reverse Transfer Capacitance	Crss	VDS=20V, f=1MHz		10		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit		6		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit		3.2		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit		16		ns
Fall Time	tf	See specified Test Circuit		4.8		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =4.8A		4.5		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =4.8A		0.9		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =4.8A		0.8		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =4.8A, V <sub>GS</sub> =0		1	1.2	V

### **Switching Time Test Circuit**





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